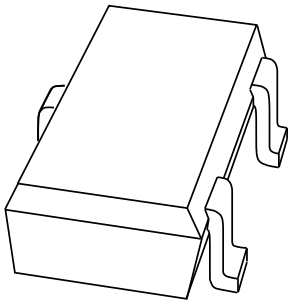
DATA SHEET



BFS540
NPN 9 GHz wideband transistor

Product specification
Supersedes data of 1997 Dec 05

2000 May 30

NPN 9 GHz wideband transistor BFS540

FEATURES

- High power gain
- Low noise figure
- High transition frequency
- Gold metallization ensures excellent reliability
- SOT323 package.

APPLICATIONS

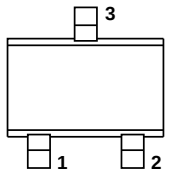
RF wideband amplifier applications such as satellite TV systems and RF portable communication equipment with signal frequencies up to 2 GHz.

DESCRIPTION

NPN transistor in a SOT323 plastic package.

PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector



Top view MBC870

Marking code: N4.

Fig.1 SOT323.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter	–	–	20	V
V_{CEO}	collector-emitter voltage	open base	–	–	15	V
I_C	DC collector current		–	–	120	mA
P_{tot}	total power dissipation	$T_s \leq 80$ °C; note 1	–	–	500	mW
h_{FE}	DC current gain	I_C = 40 mA; V_{CE} = 8 V; T_j = 25 °C	100	120	250	
f_T	transition frequency	I_C = 40 mA; V_{CE} = 8 V; f = 1 GHz; T_{amb} = 25 °C	–	9	–	GHz
G_{UM}	maximum unilateral power gain	I_C = 40 mA; V_{CE} = 8 V; f = 900 MHz; T_{amb} = 25 °C	–	14	–	dB
F	noise figure	I_C = 10 mA; V_{CE} = 8 V; f = 900 MHz; T_{amb} = 25 °C	–	1.3	1.7	dB

Note

1. T_s is the temperature at the soldering point of the collector tab.

LIMITING VALUES

In accordance with the Absolute Maximum System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter	–	20	V
V_{CES}	collector-emitter voltage	R_{BE} = 0	–	15	V
V_{EBO}	emitter-base voltage	open collector	–	2.5	V
I_C	DC collector current		–	120	mA
P_{tot}	total power dissipation	$T_s \leq 80$ °C; note 1	–	500	mW
T_{stg}	storage temperature		–65	150	°C
T_j	junction temperature		–	175	°C

Note

1. T_s is the temperature at the soldering point of the collector tab.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j\text{-}s}$	thermal resistance from junction to soldering point	$T_s \leq 80$ °C; note 1	190	K/W

Note

1. T_s is the temperature at the soldering point of the collector tab.

CHARACTERISTICS

T_j = 25 °C unless otherwise specified.

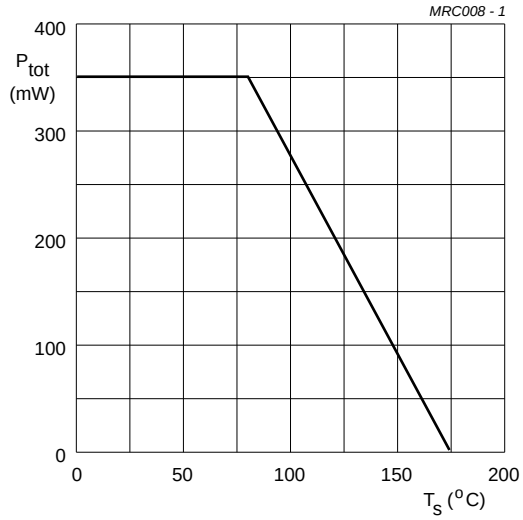
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I_{CBO}	collector cut-off current	I_E = 0; V_{CE} = 8 V	–	–	50	nA
h_{FE}	DC current gain	I_C = 40 mA; V_{CE} = 8 V	100	120	250	
C_e	emitter capacitance	$I_C = i_c$ = 0; V_{EB} = 0.5 V; f = 1 MHz	–	2	–	pF
C_c	collector capacitance	$I_E = i_e$ = 0; V_{CB} = 8 V; f = 1 MHz	–	0.9	–	pF
C_{re}	feedback capacitance	I_C = 0; V_{CB} = 8 V; f = 1 MHz	–	0.6	–	pF
f_T	transition frequency	I_C = 40 mA; V_{CE} = 8 V; f = 1 GHz; T_{amb} = 25 °C	–	9	–	GHz
G_{UM}	maximum unilateral power gain (note 1)	I_C = 40 mA; V_{CE} = 8 V; f = 900 MHz; T_{amb} = 25 °C	–	14	–	dB
		I_C = 40 mA; V_{CE} = 8 V; f = 2 GHz; T_{amb} = 25 °C	–	8	–	dB
$\lvert s_{21}\rvert^2$	insertion power gain	I_C = 40 mA; V_{CE} = 8 V; f = 900 MHz; T_{amb} = 25 °C	12	13	–	dB
F	noise figure	$\Gamma_s = \Gamma_{opt}$; I_C = 10 mA; V_{CE} = 8 V; f = 900 MHz; T_{amb} = 25 °C	–	1.3	1.8	dB
		$\Gamma_s = \Gamma_{opt}$; I_C = 40 mA; V_{CE} = 8 V; f = 900 MHz; T_{amb} = 25 °C	–	1.9	2.4	dB
		$\Gamma_s = \Gamma_{opt}$; I_C = 10 mA; V_{CE} = 8 V; f = 2 GHz; T_{amb} = 25 °C	–	2.1	–	dB
P_{L1}	output power at 1 dB gain compression	I_c = 40 mA; V_{CE} = 8 V; R_L = 50 Ω; f = 900 MHz; T_{amb} = 25 °C	–	21	–	dBm
ITO	third order intercept point	note 2	–	34	–	dBm

Notes

1. G_{UM} is the maximum unilateral power gain, assuming s_{12} is zero and

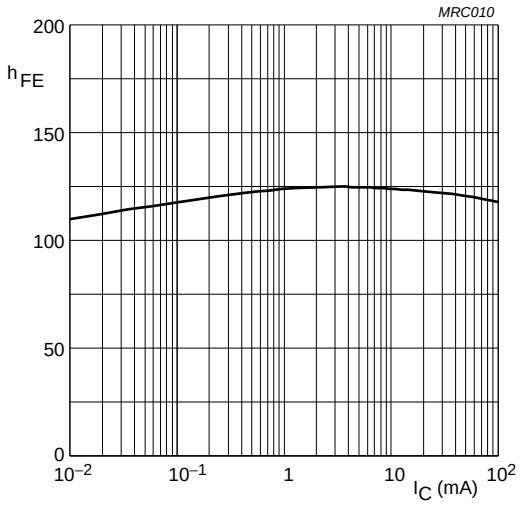
$$G_{UM} = 10 \log \frac{|s_{21}|^2}{(1-|s_{11}|^2)(1-|s_{22}|^2)} \text{ dB.}$$

2. I_C = 40 mA; V_{CE} = 8 V; R_L = 50 Ω; f = 900 MHz; T_{amb} = 25 °C; f_p = 900 MHz; f_q = 902 MHz; measured at $f_{(2p-q)}$ = 898 MHz and at $f_{(2q-p)}$ = 904 MHz.



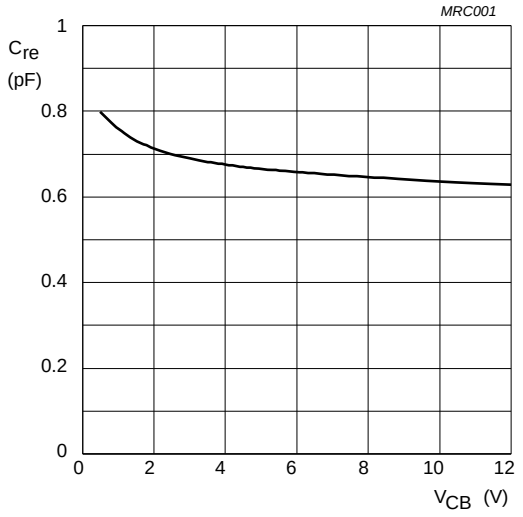
$V_{CE} \leq 10$ V.

Fig.2 Power derating curve.



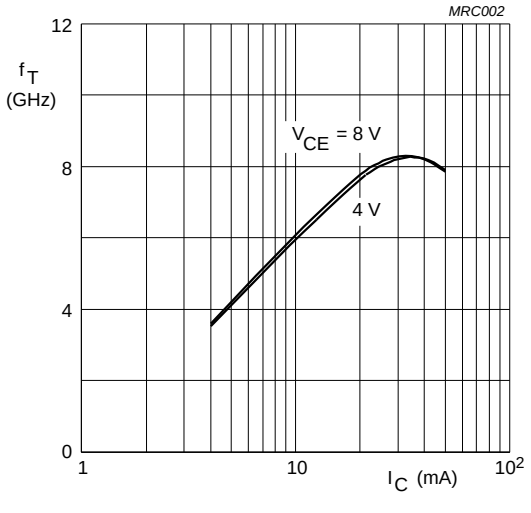
$V_{CE} = 8$ V; $T_j = 25$ °C.

Fig.3 DC current gain as a function of collector current.



$I_C = 0$; f = 1 MHz.

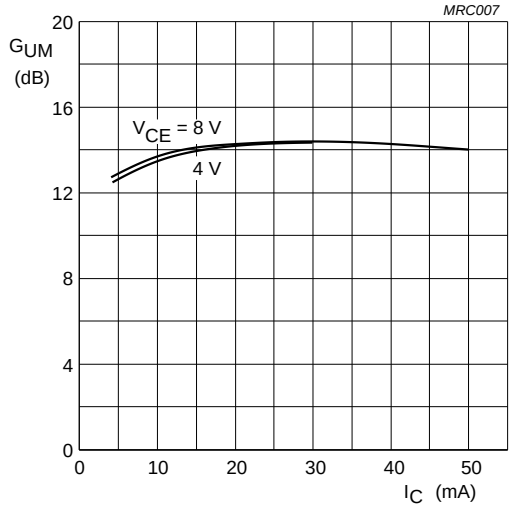
Fig.4 Feedback capacitance as a function of collector-base voltage.



f = 1 GHz; $T_{amb} = 25$ °C.

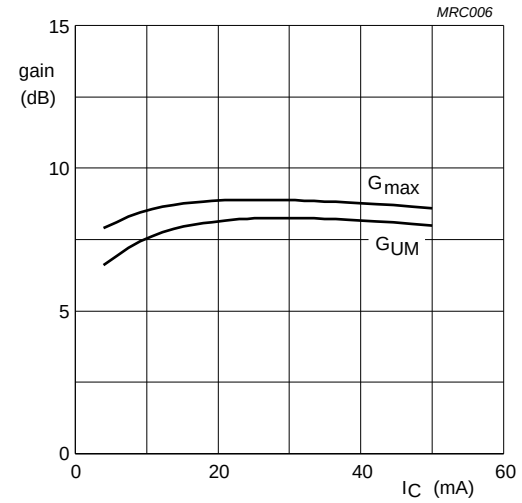
Fig.5 Transition frequency as a function of collector current.

In Figs 6 to 9, G_{UM} = maximum unilateral power gain; MSG = maximum stable gain; G_{max} = maximum available gain.



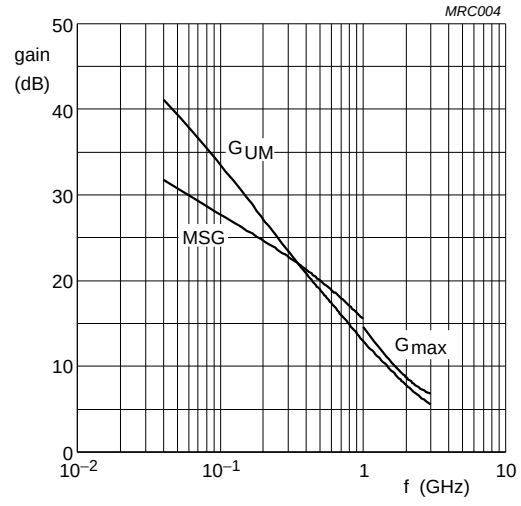
f = 900 MHz; T_{amb} = 25 °C.

Fig.6 Maximum unilateral power gain as a function of collector current.



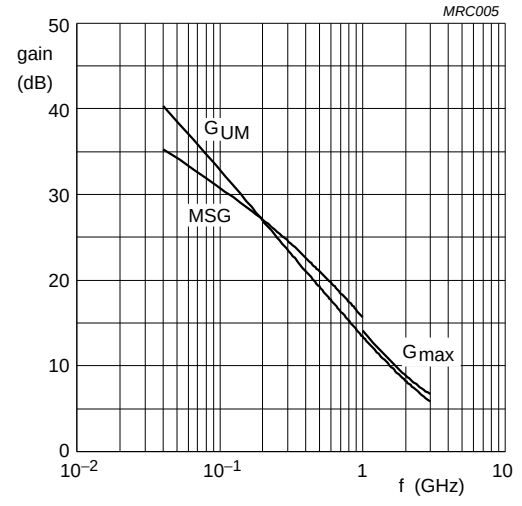
V_{CE} = 8 V; f = 2 GHz; T_{amb} = 25 °C.

Fig.7 Gain as a function of collector current.



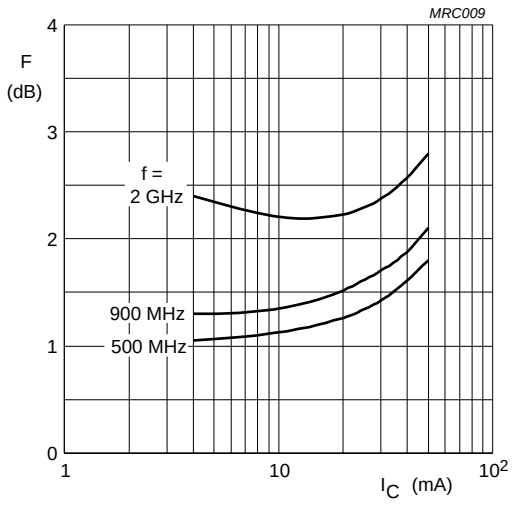
I_C = 10 mA; V_{CE} = 8 V; T_{amb} = 25 °C.

Fig.8 Gain as a function of frequency.



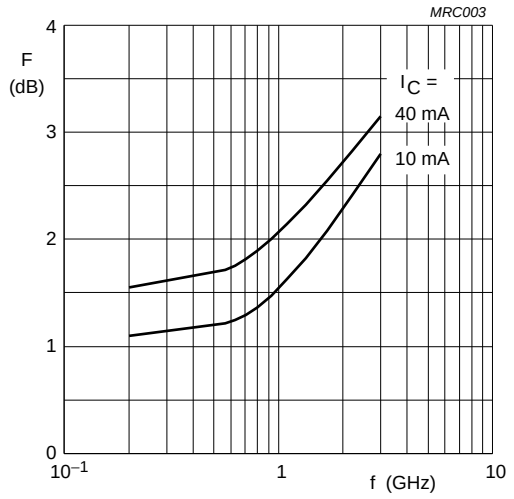
I_C = 40 mA; V_{CE} = 8 V; T_{amb} = 25 °C.

Fig.9 Gain as a function of frequency.



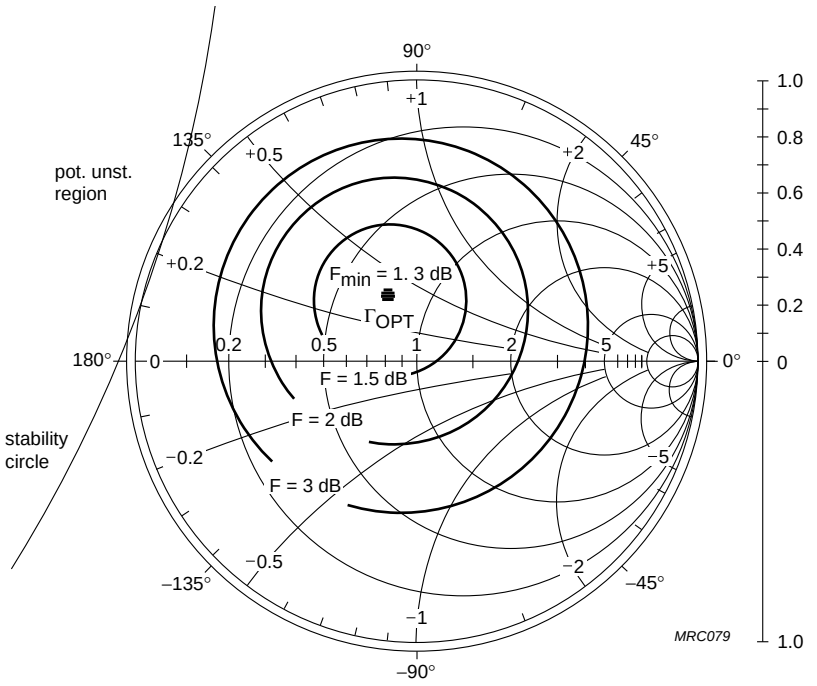
V_{CE} = 8 V; T_{amb} = 25 °C.

Fig.10 Minimum noise figure as a function of collector current.



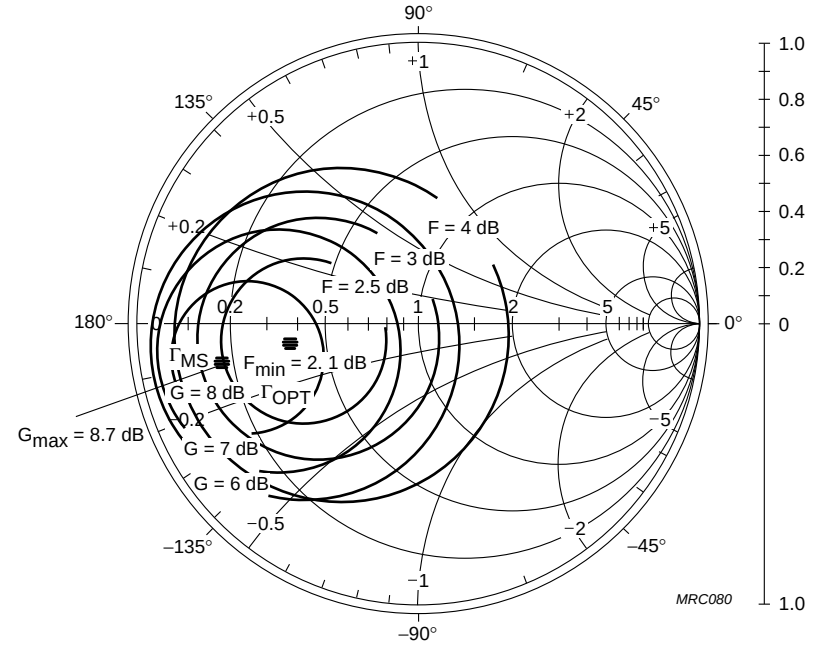
V_{CE} = 8 V; T_{amb} = 25 °C.

Fig.11 Minimum noise figure as a function of frequency.



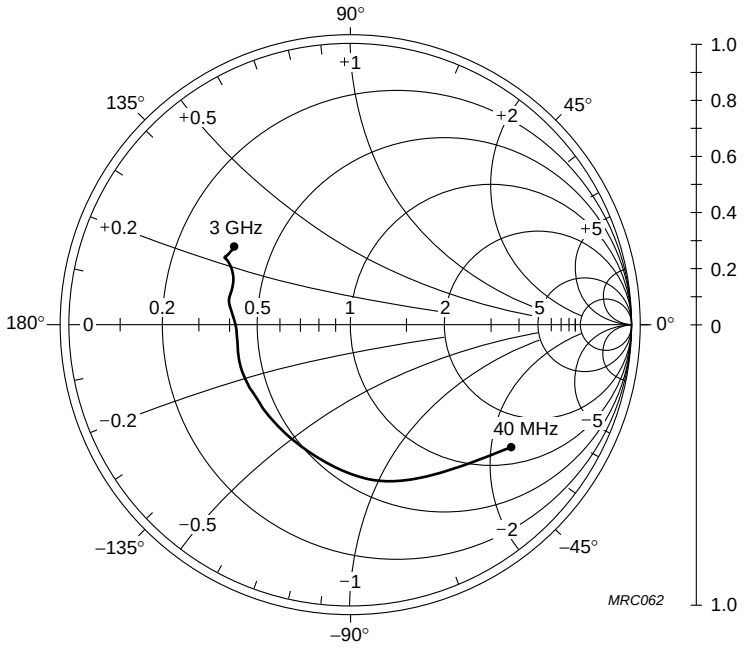
I_C = 10 mA; V_{CE} = 8 V;
f = 900 MHz; Z_o = 50 Ω.

Fig.12 Noise circle.



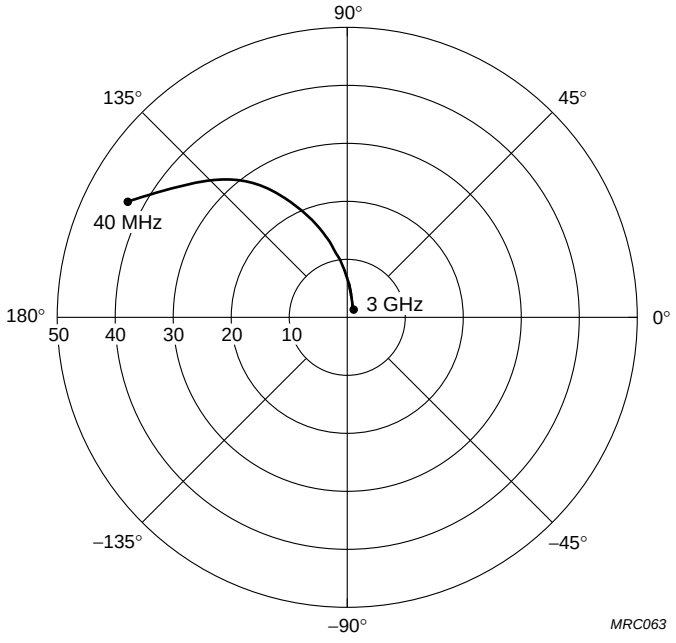
I_C = 10 mA; V_{CE} = 8 V;
f = 2 GHz; Z_o = 50 Ω.

Fig.13 Noise circle.



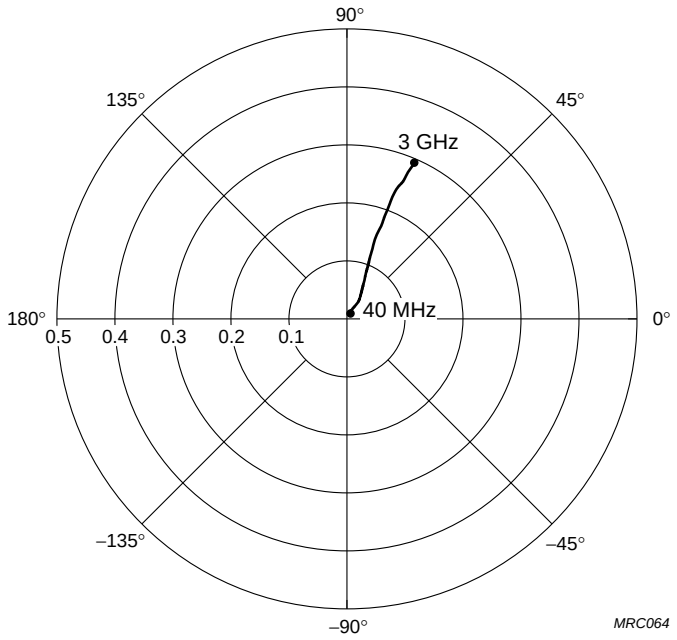
I_C = 40 mA; V_{CE} = 8 V;
Z_o = 50 Ω.

Fig.14 Common emitter input reflection coefficient (s_{11}).



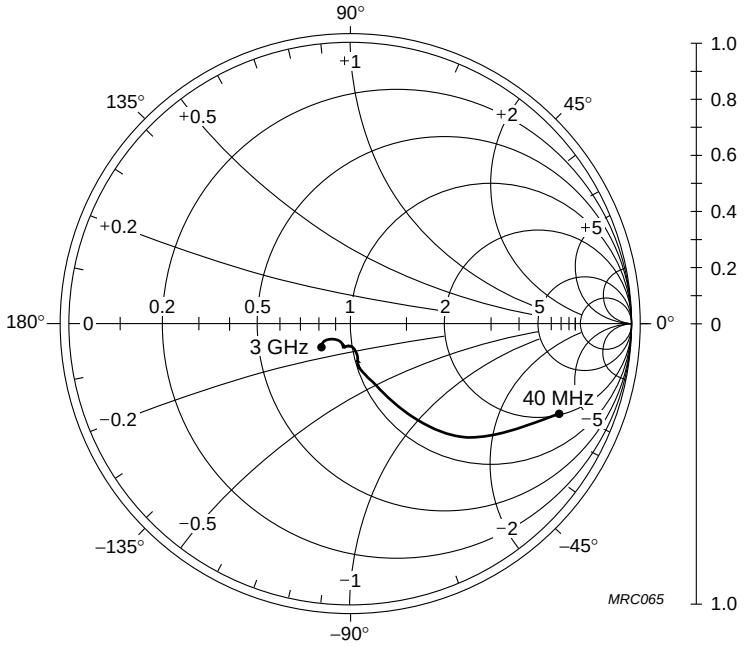
I_C = 40 mA; V_{CE} = 8 V.

Fig.15 Common emitter forward transmission coefficient (s_{21}).



I_C = 40 mA; V_{CE} = 8 V.

Fig.16 Common emitter reverse transmission coefficient (s_{12}).

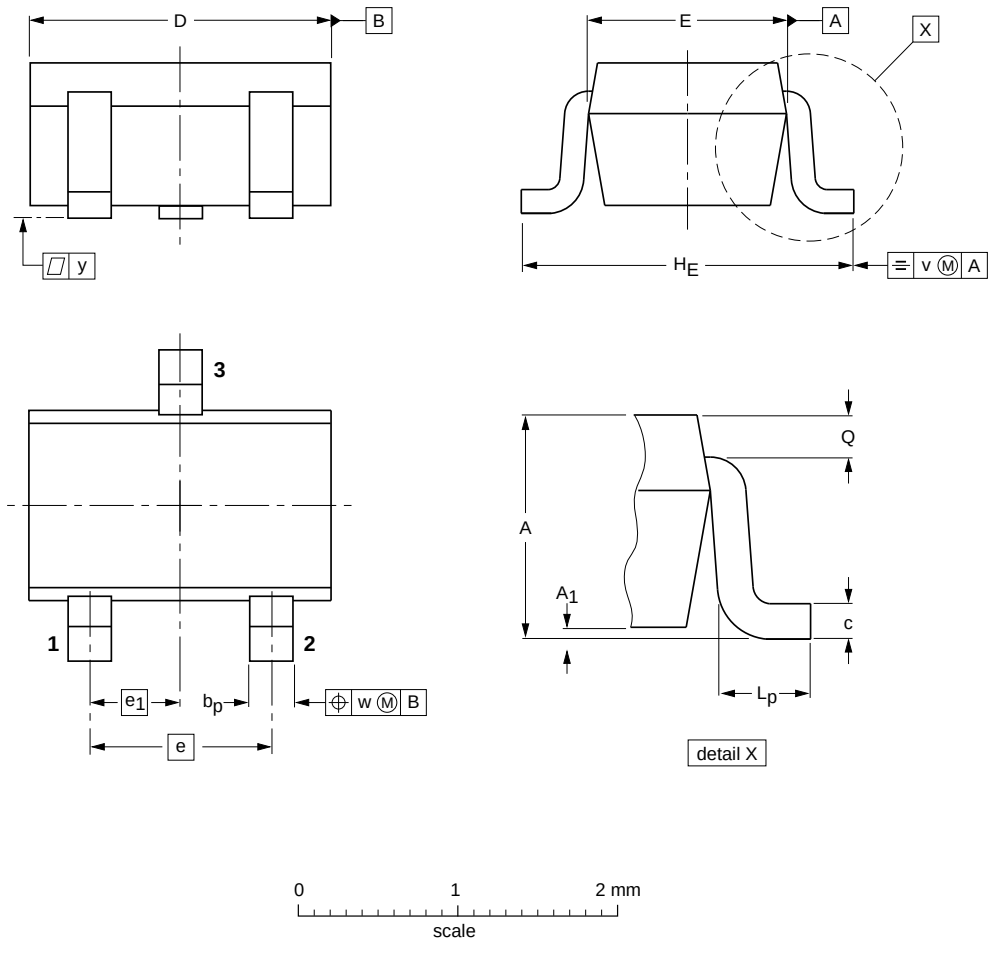


I_C = 40 mA; V_{CE} = 8 V;
Z_o = 50 Ω.

Fig.17 Common emitter output reflection coefficient (s_{22}).

PACKAGE OUTLINE

Plastic surface-mounted package; 3 leads **SOT323**



DIMENSIONS (mm are the original dimensions)

UNIT	A	A_1 max	b_p	c	D	E	e	e_1	H_E	L_p	Q	v	w
mm	1.1 0.8	0.1	0.4 0.3	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.23 0.13	0.2	0.2

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT323			SC-70			~~04-11-04~~ 06-03-16

DATA SHEET STATUS

DOCUMENT STATUS[1]	PRODUCT STATUS[2]	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

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